NSN 5961-01-059-6784

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View Online at https://aerobasegroup.com/nsn/5961-01-059-6784 **Inclosure Material:** Metal **Overall Length:** Between 0.051 inches and 0.071 inches Overall Diameter: Between 0.098 inches and 0.102 inches **Function For Which Designed:** Oscillator **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.099 inches **Semiconductor Material:** Gallium arsenide Voltage Rating In Volts Per Characteristic: 16.0 off-state voltage, dc **Current Rating Per Characteristic:** 1.90 amperes source cutoff current of standard range **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 85.0 degrees celsius case **Special Features:** 4.40 to 5.0 ghz; junction pattern arrangement: np **Precious Material And Location:** Case gold **Precious Material:** Gold **Test Data Document:** 28528-1133241 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 threaded stud and 1 ferrule

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N/a

Shelf Life:

Unit Of Measure:

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Demilitarization:

No

Fiig:

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